To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

SILICON TRANSISTOR ARRAY

Phase-out/Discontinued

μPA1427

PNP SILICON POWER TRANSISTOR ARRAY
LOW SPEED SWITCHING USE (DARLINGTON TRANSISTOR)
INDUSTRIAL USE

DESCRIPTION

The μPA1427 is PNP silicon epitaxial Darlington Power Transistor Array that built in 4 circuits designed for driving solenoid, relay, lamp and so on.

FEATURES

- Easy mount by 0.1 inch of terminal interval.
- High h_{FE} for Darlington Transistor.

ORDERING INFORMATION

Part Number	Package	Quality Grade
μPA1427H	10 Pin SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

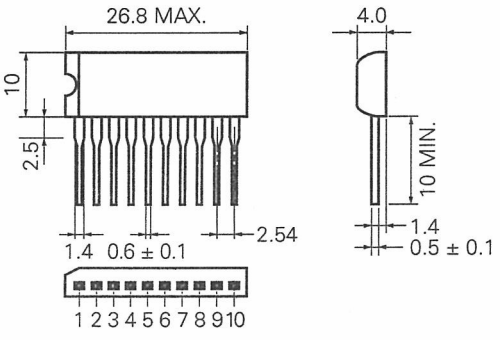
ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

Collector to Base Voltage	V_{CBO}	–80	V
Collector to Emitter Voltage	V_{CEO}	–80	V
Emitter to Base Voltage	V_{EBO}	–7	V
Collector Current (DC)	$I_{C(DC)}$	∓2	A/unit
Collector Current (pulse)	$I_{C(pulse)}$*	∓4	A/unit
Base Current (DC)	$I_{B(DC)}$	–0.2	A/unit
Total Power Dissipation (T_a = 25 °C)	P_{T1}**	3.5	W
Total Power Dissipation (T_C = 25 °C)	P_{T2}**	28	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

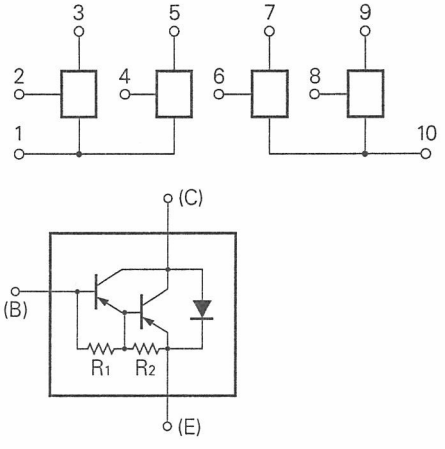
* PW ≦ 300 μs, Duty Cycle ≦ 10 %

** 4 Circuits

PACKAGE DIMENSION
(in millimeters)



CONNECTION DIAGRAM



PIN No.

2, 4, 6, 8: Base (B)
3, 5, 7, 9: Collector (C)
1, 10: Emitter (E)
R_1 ≒ 10 kΩ
R_2 ≒ 500 Ω

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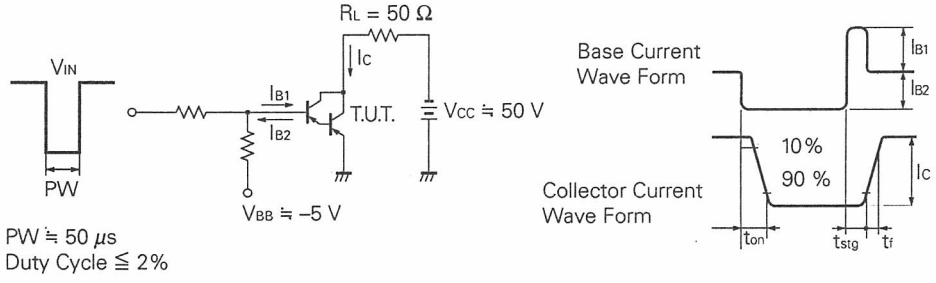
Document No. IC–3465
(O.D. No. IC–6337)
Date Published August 1994 M
Printed in Japan

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Leakage Current	I_{CBO}			−10	μA	V_{CB} = −80 V, I_E = 0
Emitter Leakage Current	I_{EBO}			−1	mA	V_{EB} = −5 V, I_C = 0
DC Current Gain	h_{FE1}*	1 000	8 000		—	V_{CE} = −2 V, I_C = −0.5 A
DC Current Gain	h_{FE2}*	2 000	9 000	30 000	—	V_{CE} = −2 V, I_C = −1 A
Collector Saturation Voltage	$V_{CE(sat)}$*		−1.1	−1.5	V	I_C = −1 A, I_B = −1 mA
Base Saturation Voltage	$V_{BE(sat)}$*		−1.6	−2	V	I_C = −1 A, I_B = −1 mA
Turn-On Time	t_{on}		0.5		μs	I_C = −1 A, I_{B1} = −I_{B2} = −1 mA V_{CC} ≒ −50 V, R_L = 50 Ω See test circuit
Storage Time	t_{stg}		1		μs	
Fall Time	t_f		1		μs	

*PW ≦ 350 μs, Duty Cycle ≦ 2% / pulsed

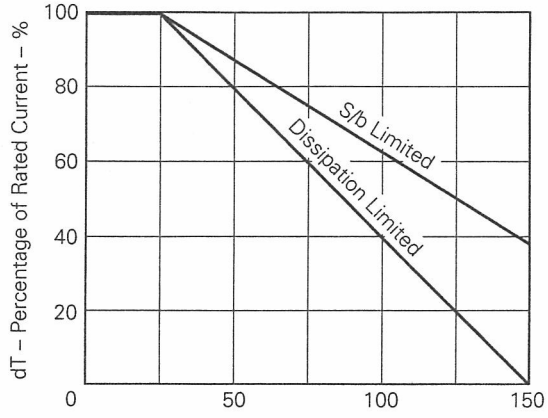
SWITCHING TIME TEST CIRCUIT



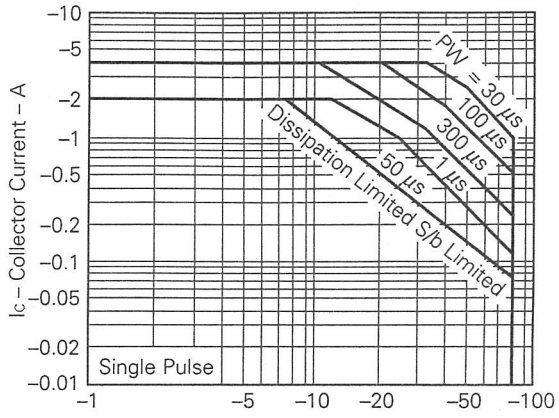
Phase-out/Discontinued

TYPICAL CHARACTERISTICS (T_a = 25 °C)

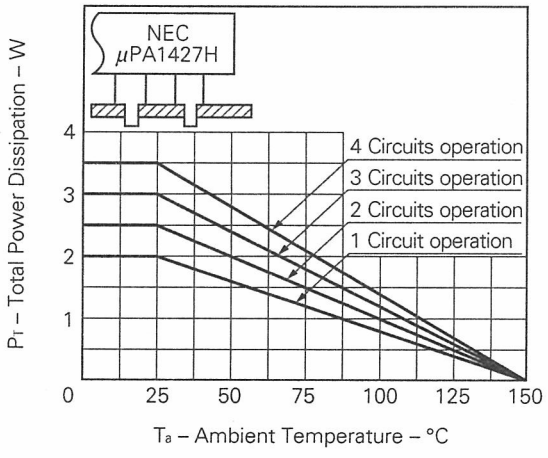
DERATING CURVE OF SAFE OPERATING AREA



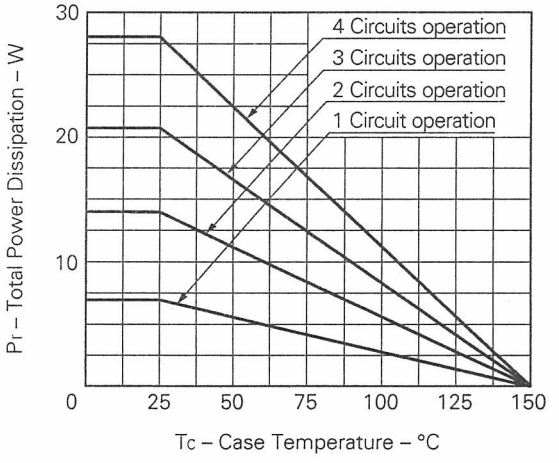
SAFE OPERATING AREA



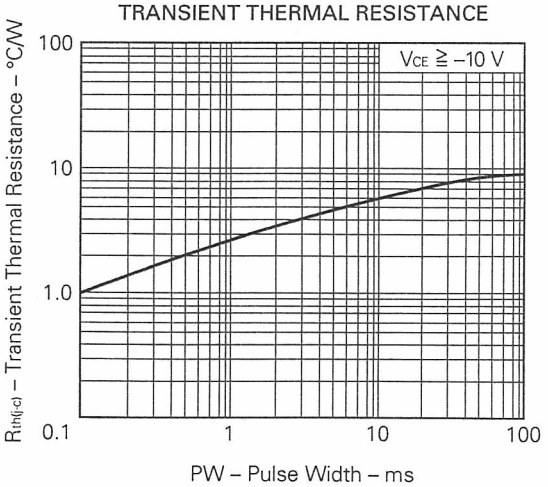
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



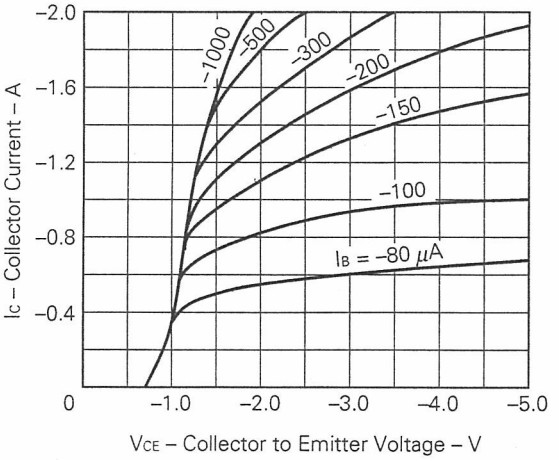
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



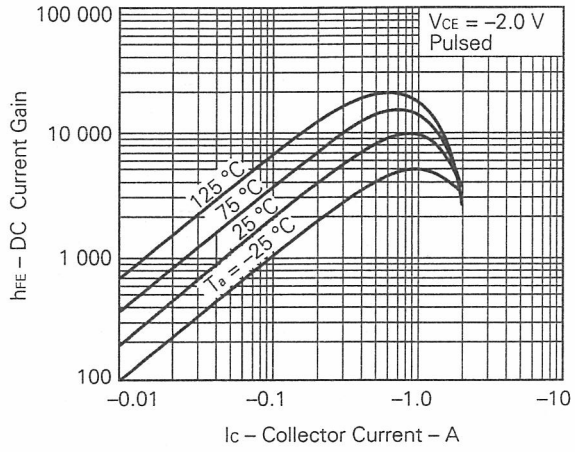
TRANSIENT THERMAL RESISTANCE



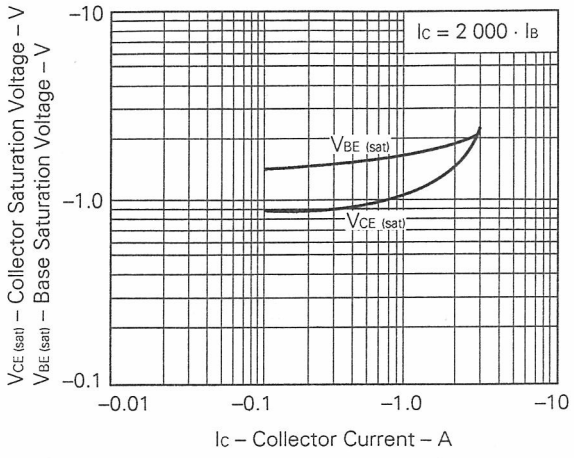
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



DC CURRENT GAIN vs. COLLECTOR CURRENT



BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

[MEMO]

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